UNISONIC TECHNOLOGIES CO., LTD

UH8100 cmos ic

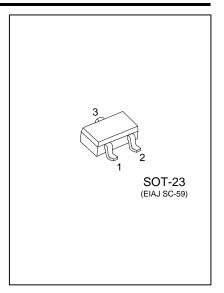
LOW POWER HALL EFFECT SWITCH

DESCRIPTION

UH8100 is a low-power integrated Hall switch designed to sense the applied magnetic flux density and give a digital output, which indicates the present condition of the magnitude sensed.

It mainly designed for battery-powered system and hand-held equipment, such as cellular flip-phones and PDA's, in which power consumption is one major concern. The typical power consumption of **UH8100** is down to 15uW at 2.75V supply.

For **UH8100**, the output will be high when no magnetic field is applied and be low when the applied magnetic flux density is stronger than the switching threshold. The difference between **UH8100A** and **UH8100B** is that **UH8100A** consumes less power than **UH8100B** in the Hall sensor operation.



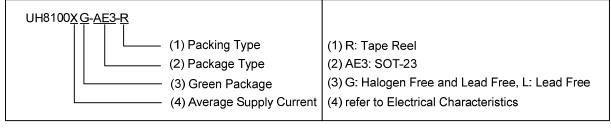
■ FEATURES

- * Micro power Operation
- * 2.5V to 5.5V Battery Operation
- * Offset Canceling Technology
- * Superior Temperature Stability
- * Extremely Low Switch-Point Drift
- * Insensitive to Physical Stress

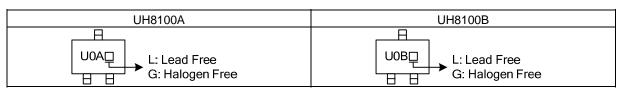
■ ORDERING INFORMATION

| Ordering Number | | Dookogo | Pin Assignment | | | Dooking | |
|-----------------|----------------|---------|----------------|---|---|-----------|--|
| Lead Free | Halogen Free | Package | 1 | 2 | 3 | Packing | |
| UH8100AL-AE3-R | UH8100AG-AE3-R | SOT-23 | ı | 0 | G | Tape Reel | |
| UH8100BL-AE3-R | UH8100BG-AE3-R | SOT-23 | I | 0 | G | Tape Reel | |

Note: Pin Assignment: I: V_{DD} O: V_{OUT} G: GND



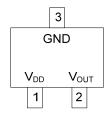
■ MARKING



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■ PIN CONFIGURATIONS

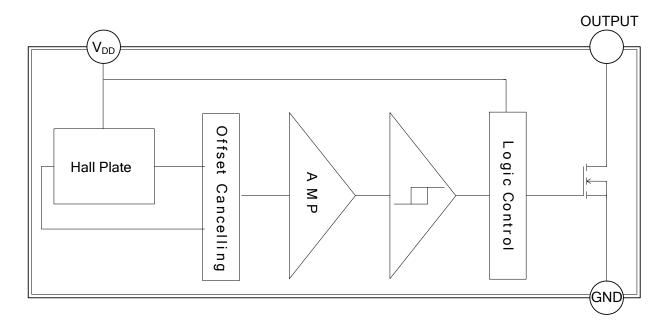


■ PIN DESCRIPTION

| PIN NO. | PIN NAME | PIN TYPE | PIN DESCRIPTION |
|---------|-----------|----------|-----------------|
| 1 | V_{DD} | Р | Power Supply |
| 2 | V_{OUT} | 0 | Digital Output |
| 3 | GND | G | Ground |

Note: O=Output, P=Power Supply, G=Ground

■ BLOCK DIAGRAM



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■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

| PARAMETER | SYMBOL | RATINGS | UNIT |
|---------------------------|------------------|--------------------|------|
| Magnetic Flux Density | В | Unlimited | mT |
| Supply Voltage | V_{DD} | 7 | V |
| Output Current | Io | 10 | mA |
| Package Power Dissipation | P_{D} | 230 | mW |
| Junction Temperature | T_J | +150 | °C |
| Operation Temperature | T_OPR | -40 ~ +85 | °C |
| Storage Temperature | T _{STG} | -65 ~ + 150 | °C |

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **RECOMMENDED OPERATING CONDITIONS** (T_A=25°C, unless otherwise specified)

| PARAMETER | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------|----------|------------|-----|-----|-----|------|
| Supply Voltage | V_{DD} | Operating | 2.5 | | 5.5 | V |

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise specified)

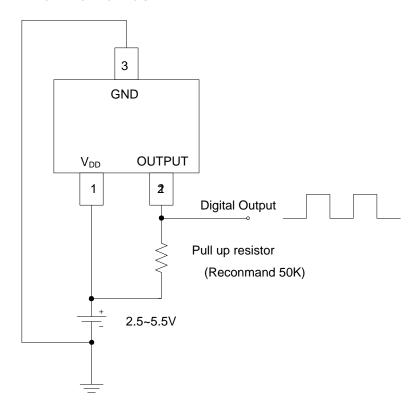
| PARAMETER | SYMBOL | CONDITIONS | | MIN | TYP | MAX | UNIT |
|------------------------|----------------------|------------------------------------|---------|-----|------|-----|------|
| Output On Voltage | V_{OUT} | $V_{DD}=3V$, $I_{OUT}=1mA$ | | | 0.1 | 0.3 | V |
| Output Leakage Current | I _{OFF} | $V_{DD}=3V$, $V_{OUT}=5.5V$, B | | | 0.01 | 1 | uA |
| Supply Current | I _{DD(AVG)} | $V_{DD}=3V$, | UH8100A | | 5 | 10 | uA |
| | | average supply current | UH8100B | | 280 | 500 | uA |
| Awake Time | T _{AWAKE} | V _{DD} =3V | | | 50 | 100 | us |
| Period | T _{PERIOD} | V _{DD} =3V,UH8100A | | | 50 | 100 | ms |
| | | V _{DD} =3V,UH8100B | | | 200 | 400 | us |
| Duty Cycle | 1)(: | V _{DD} =3V,UH8100A | | | 0.1 | | % |
| | | V _{DD} =3V,UH8100B | | | 25 | | % |

■ MAGNETIC CHARACTERISTICS (T_A=25°C, V_{DD}=3V, unless otherwise specified)

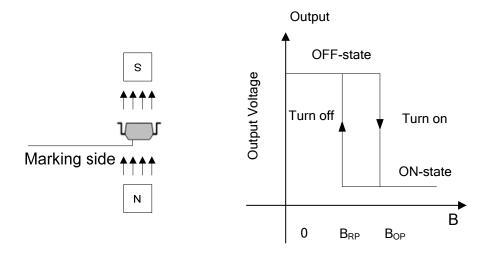
| PARAMETER | SYMBOL | MIN | TYP | MAX | UNIT |
|------------------|----------------------------------|-----|-----|-----|-------|
| Operation Points | B _{OP} | | 40 | 60 | |
| Release Points | B _{RP} | 10 | 30 | | Gauss |
| Hysteresis | B _{OP} -B _{RP} | | 10 | | |

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■ TYPICAL APPLICATION CIRCUIT



■ MAGNETIC FLUX



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